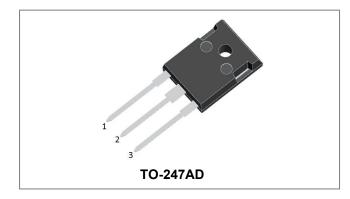


Technical Data Data Sheet N1707, Rev. B





40CPQ15 SCHOTTKY RECTIFIER



Features

- 100 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	$V_{RRM} \ V_{RWM}$	-	15	V
DC Blocking Voltage	V_R			
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=75°C, rectangular wave form	20(Per Leg) 40(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, T _C = 25 °C	120	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per Leg)*	V _{F1}	@ 20A, Pulse, T _J = 25 °C @ 40A, Pulse, T _J = 25 °C	-	0.42 0.50	V
	V _{F2}	@ 20A, Pulse, T _J = 125 °C @ 40A, Pulse, T _J = 125 °C	-	0.33 0.42	V
Reverse Current (Per Leg)*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	-	10.5	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	-	2500	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $^{^*\,}$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •



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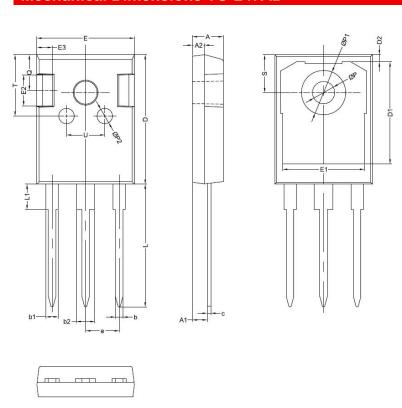




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +100	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(per leg)	$R_{ heta JC}$	DC operation	1.4	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AD			

Mechanical Dimensions TO-247AD



CVMDOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A1	2.20	2.41	2.61	
A2	1.90	2.00	2.10	
b	1.10	1.20	1.40	
b1	1.80	2.00	2.20	
b2	2.80	3.00	3.20	
С	0.50	0.60	0.75	
D	20.30	21.00	21.20	
D1		16.55		
D2		1.20		
D2 E	15.45	15.80	16.00	
E1		13.30		
E2		5.00		
E3		2.50		
е		5.44		
L	19.42	19.92	20.70	
L1		4.13		
Р	3.50	3.60	3.70	
P1	7.1		7.40	
P2		2.50		
Q		5.80		
Q S T	6.05	6.15	6.25	
T		10.00		
U		6.20		

Ordering Information:

Device	Package	Shipping	
40CPQ015	TO-247AD(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

[•] http://www.smc-diodes.com - sales@ smc-diodes.com •

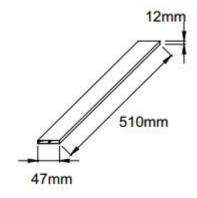


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Tube Specification



Marking Diagram



Where XXXXX is YYWWL

= Forward Current (40A) = Configuration PQ = Device Type = Reverse Voltage (15V) 015 SSG = SSG = Year ww = Week = Lot Number Cautions: Molding resin

Epoxy resin UL:94V-0

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